MT9222

RoHS

Fully Integrated, Hall Effect-Based Linear Current Sensor IC with 4.8 kV High-Isolation SOP-16 Wide Body Package
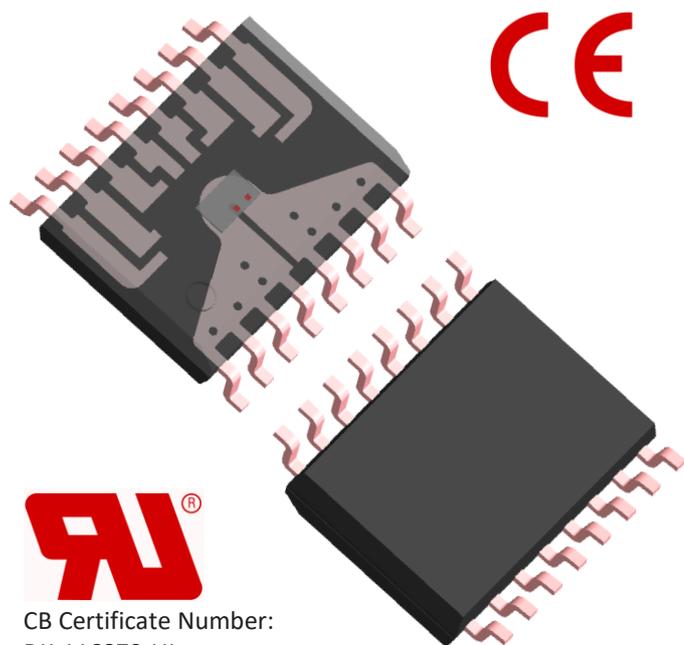
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1 Product Description

The MagnTek® MT9222 product series is a fully integrated Hall Effect-based isolated linear current sensor device family designed for AC or DC current sensing in industrial, commercial, and communications systems. Each of the MT9222 consists of a precise, low-offset, linear Hall circuit with a low-resistance current conductor path located near the surface of the die. Applied current flowing through this low-resistance current conductor path generates a magnetic field that the Hall IC converts into a proportional voltage. The current is sensed differentially in order to reject common-mode fields, improving accuracy in magnetically noisy environments. Device accuracy is optimized through the close proximity of the magnetic field to the Hall transducer.

A precise, proportional voltage is provided by the low-offset, chopper-stabilized BCD Hall IC, which has been accurately calibrated when it is manufactured. The output of the device has a positive slope ($>V_{OQ}$) when an increasing current flows through the primary current conduction path (from pins 1,2,3 and 4, to pins 5,6,7 and 8). The internal resistance of this conductive path is 0.85 mΩ typical, providing low-power loss. The terminals of the conductive path are electrically isolated from the signal leads (pins 9 through 16). This allows the MT9222 current sensor IC to be used in high-side current sense applications without use other costly isolation techniques.

The MT9222 family provides SOP-16W package to customers, The package is RoHS compliant.

2 Features

- ±0.5% Typical Linearity Over Temperature
- Fast Output Response Time: 4 μs (typ.)
- 150kHz Signal Bandwidth
- 5.0V Single Supply Operation
- -40℃~125℃ Operating Temperature
- Primary Conductor Resistance
  ---0.85mΩ
- Sensing Current Range: (AC or DC)
  ---±20A, ±25A, ±30A, ±50A, ±65A
  ---+40A, +50A
- Output Voltage Proportional to AC or DC Current
- Ratiometric Output from Supply Voltage
- Extremely Stable Quiescent Output Voltage
- Device Bandwidth is Set via FILTER Pin
- Near Zero Magnetic Hysteresis
- Safety Parameters: (CB Certificate Number: DK-116879-UL)
  ---4.8kVrms 1min Dielectric Surge Isolation
  ---1097Vrms, 1550V$_{DC}$ or V$_{PK}$ Working Voltage
  ---7.5mm Clearance Distance
  ---8.2mm Creepage Distance
- Package Option:
  ---SOP-16W
- RoHS Compliant: (EU)2015/863

3 Applications

- Low-power inverter current sensing
- Motor phase and rail current sensing
- PV String Inverters
- Chargers and Converters
- Switching Power Supplies
- Overcurrent Protection
- UPS Power

CE

CB Certificate Number:
DK-116879-UL

Not to scale

4 Product Overview of MT9222

Part No.	Description
MT9222WT	SOP-16W Tape & Reel (1000 pcs/bag)

Table of Contents

Reversion History

1   Originally Version
2   1.0 Version   Update Logo and UL CB Certificate Number

MT9222
Fully Integrated, Hall Effect-Based Linear Current Sensor IC with
4.8 kV High-Isolation SOP-16 wide Body Package

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5 Functional Block Diagram
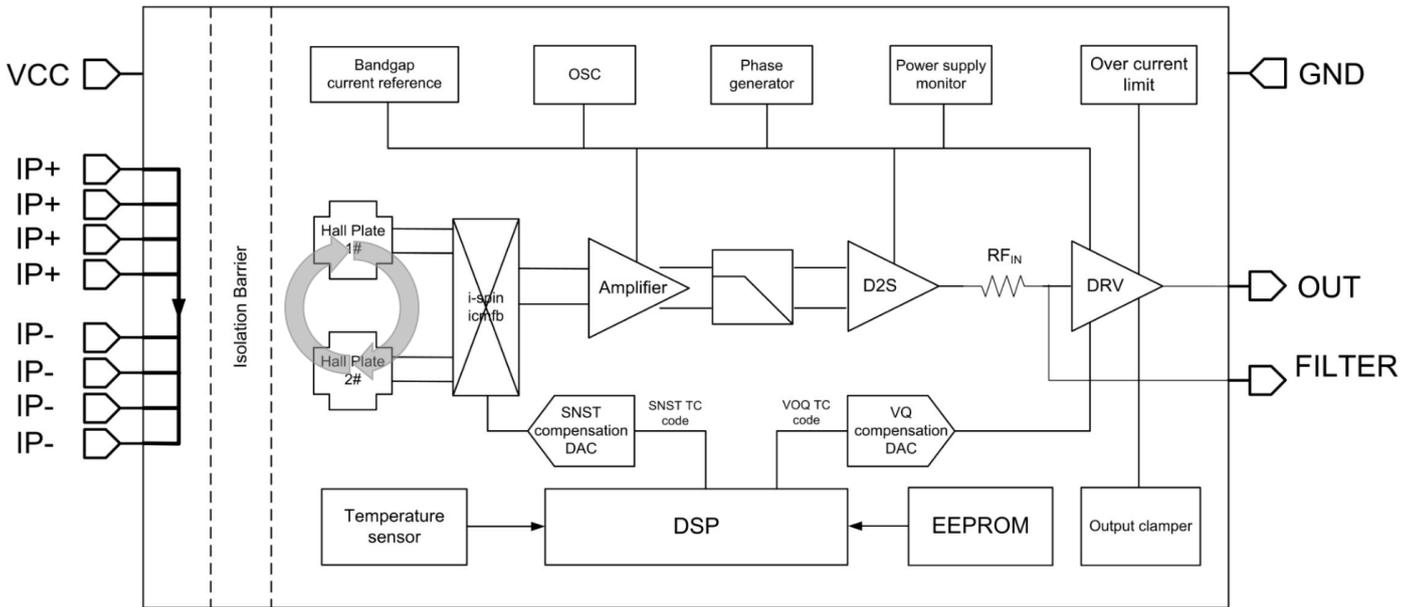
Figure.1   Functional Block Diagram

6 Pin Configuration and Functions

Top View
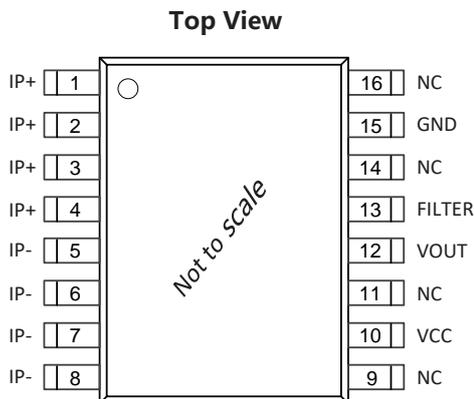
No.	Name	Description
1, 2, 3, 4	IP+	Input Current Positive Pin
5, 6, 7, 8	IP-	Input Current Negative Pin
9	NC	No Internal Connection
10	VCC	Power Supply
11	NC	No Internal Connection
12	VOUT	Analog Output Signal
13	FILTER	Filter Pin to Set Bandwidth
14	NC	No Internal Connection
15	GND	Signal Ground
16	NC	No Internal Connection

Figure.2   Pin Configuration & Functions (SOP-16W)

MT9222
Fully Integrated, Hall Effect-Based Linear Current Sensor IC with
4.8 kV High-Isolation SOP-16 wide Body Package

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7 Naming Specification

Part Number | MT9222 | WT | - | 50 | B | R | 5
❶ ❷ ❸ ❹ ❺ ❻
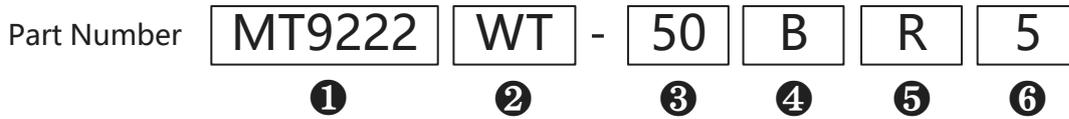
❶ Series Name

❷ Package Type

Type	Package Type
WT	SOP-16W

❸ Input Current Range

Type	Input Current Range
20	Full scale sensing range: 20A
25	Full scale sensing range: 25A
30	Full scale sensing range: 30A
40	Full scale sensing range: 40A
50	Full scale sensing range: 50A
65	Full scale sensing range: 65A

❹ Current Polarity

Type	Current Polarity
B	Bidirectional---AC Current
U	Unidirectional---DC Current

❺ Output Mode

Type	Output Mode
R	Ratiometry output

❻ Power Supply

Type	Power Supply
5	VCC=5V

8 Selection Guide

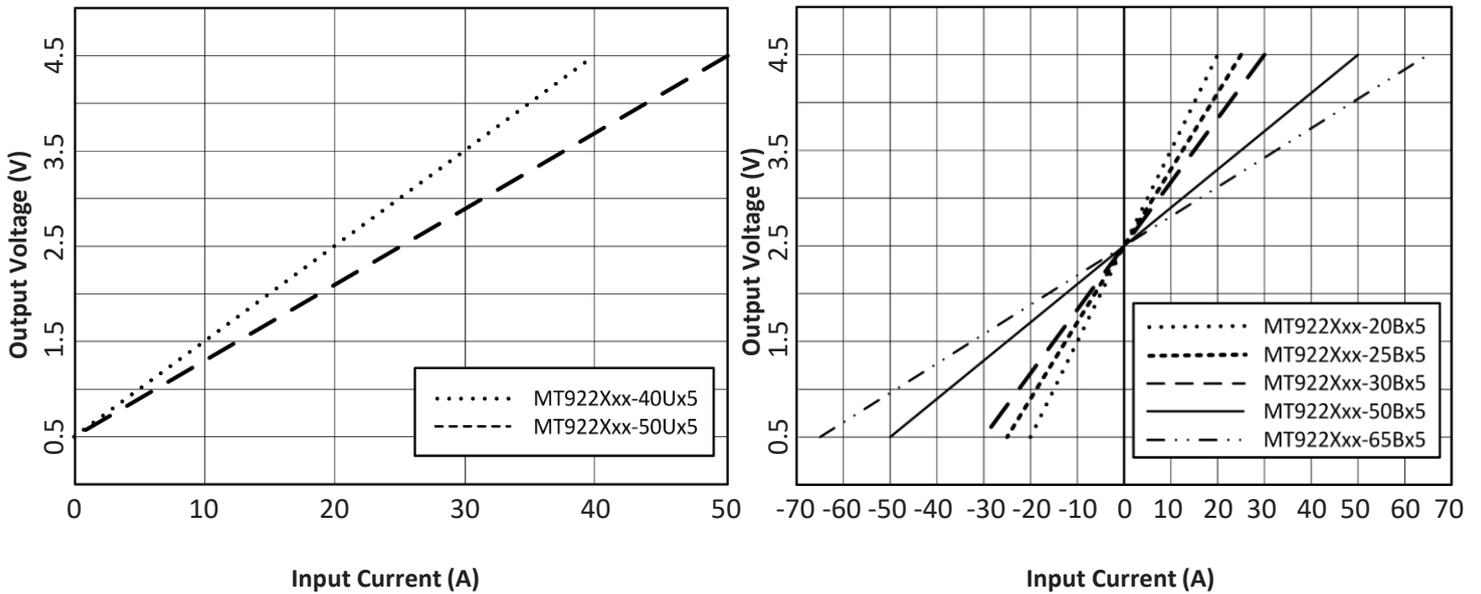| Ordering Part Number	Current Range (A)	VCC (V)	Sensitivity (mV/A)	Package	Qty per Reel (pcs)
MT9222WT-40UR5	+40	5	100	SOP-16W	1000
MT9222WT-50UR5	+50	5	80	SOP-16W	1000
MT9222WT-20BR5	±20	5	100	SOP-16W	1000
MT9222WT-25BR5	±25	5	80	SOP-16W	1000
MT9222WT-30BR5	±30	5	66.7	SOP-16W	1000
MT9222WT-50BR5	±50	5	40	SOP-16W	1000
MT9222WT-65BR5	±65	5	30.8	SOP-16W	1000

9 Output Voltage vs. Input Current

Figure.3   Output Voltage vs. Input Current

10 Typical Application Circuit

The typical application circuits of MT9222 series products include a bypass capacitor (**C**BYPASS **capacitor between VCC and GND is necessary)** and a filter capacitor as an additional external components. On the input side, pins 1,2,3 and 4 are shorted together, pins 5,6,7 and 8 are shorted together. The analog signal output is measured directly from the VOUT pin. The signal is proportional to the IP of the primary sensing current of AC or DC within the specified measurement range. **The FILTER pin can be used to reduce bandwidth to optimize noise performance, but at the same time proportionally increase response time**. **C**FILTER **Recommends "Open", and the response time is the fastest.**
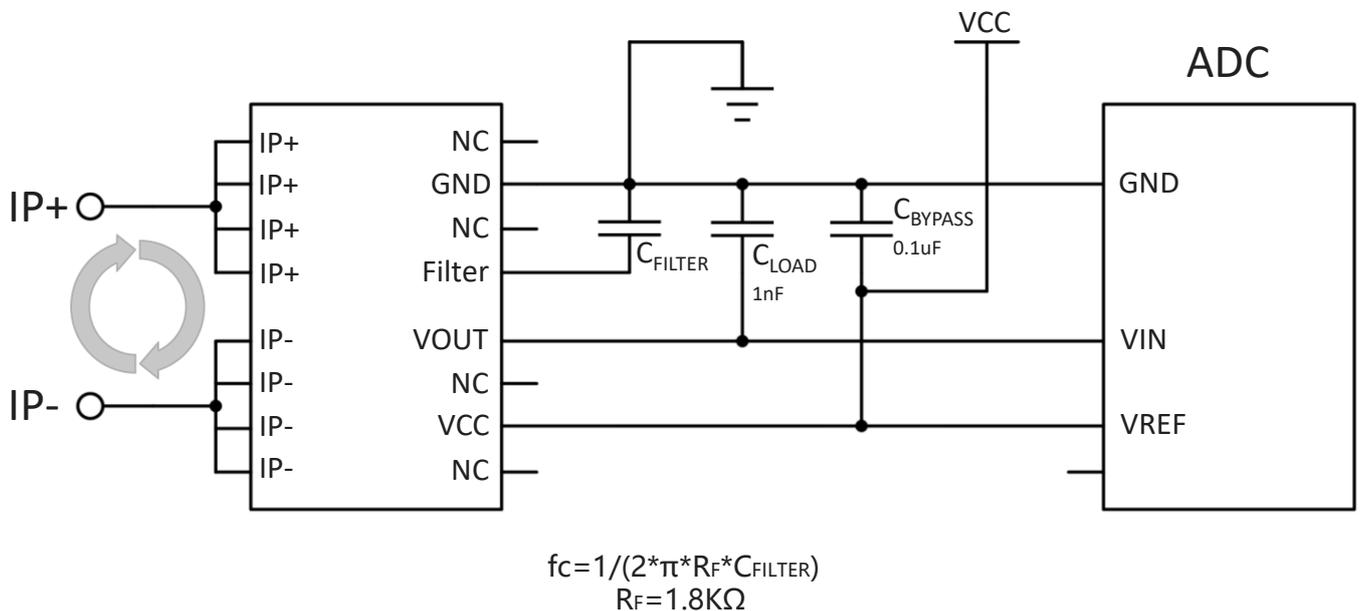

$$fc=1/(2*\pi*R_F*C_{FILTER})$$
$$R_F=1.8K\Omega$$

Figure.4   Typical Application Circuit

MT9222
Fully Integrated, Hall Effect-Based Linear Current Sensor IC with
4.8 kV High-Isolation SOP-16 wide Body Package

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11 Electrical Magnetic Characteristics

11.1 Absolute Maximum Ratings

Absolute maximum ratings are limited values to be applied individually, and beyond which the serviceability of the circuit may be impaired. Functional operability is not necessarily implied. Exposure to absolute maximum rating conditions for an extended period of time may affect device reliability.

Symbol	Parameters	Min	Max	Units
VCC	Supply Voltage	-	6	V
VRCC	Reverse Battery Voltage	-0.1	-	V
VOUT	Output Voltage	-	VCC+0.5	V
VROUT	Reverse Output Voltage	-0.1	-	V
IOUT(source)	Continuous Output Current	-	80	mA
IOUT(sink)	Continuous Output Current	-	40	mA
TA	Operating Ambient Temperature	-40	125	℃
TS	Storage Temperature	-50	150	℃
TJ	Junction Temperature	-	175	℃

11.2 Isolation and Package Characteristics

Symbol	Parameters	Test Conditions	Value	Units
V_{SURGE}	Dielectric Surge Strength Test Voltage	Tested ±5 pulses at 30 seconds in compliance to IEC 61000-4-5 1.2 / 50 µs (width).	10000	V
I_{SURGE}	Surge Current	Tested ±5 pulses at 30 seconds in compliance to IEC 61000-4-5 8 / 20 µs (width).	13000	A
V_{ISO}	Dielectric Strength Test Voltage	Test method per UL standard 60950-1 (edition 2). $V_{TEST} = V_{ISO}$, t = 60 s (qualification); $V_{TEST} = 1.2 \times V_{ISO}$, t = 1 s (100% production)	4800	Vrms
V_{IOWM}	Maximum Working Isolation Voltage	Maximum working voltage for Basic isolation according to UL60950-1	1550	V_{PK} or V_{DC}
			1097	Vrms
CTI	Comparative Tracking Index	Comparative tracking index according to IEC60112:2009	600	V
D_{CL}	External Clearance	Measured from input terminals to output terminals, shortest distance through air.	7.5	mm
D_{CR}	External Creepage	Measured from input terminals to output terminals, shortest distance path along body.	8.2	mm

11.3 Life Time Characteristics

Symbol	Parameters	Test Condition	Min	Typ	Max	Unit
ESNST_DRIFT	Sensitivity Error Lifetime Drift	TA=-40~125℃	-	±3	-	%
ETOT_DRIFT	Total Output Error Lifetime Drift	TA=-40~125℃	-	±3	-	%

* Based on characterization data obtained during AEC-Q100 stress testing.

11.4 ESD Ratings

Parameters	Reference	Grade
Human-body model (HBM)	AEC-Q100-002	Class IIIA
Charged-device model (CDM)	AEC-Q100-011	Class C3
Latch up	AEC-Q100-004	Class IIA

11.5 Electrical Specifications

At TA =-40~125 ℃, Vcc=5V (unless otherwise specified)

Symbol	Parameters	Test Condition	Min	Typ	Max	Unit
VCC	Supply Voltage	-	4.5	5	5.5	V
ICC	Supply Current	TA = 25°C	-	14	20	mA
RIP	Primary Conductor Resistance	TA = 25°C	-	0.85	-	mΩ
BW	Internal Bandwidth	Small signal –3 dB; CL = 1 nF	-	150	-	KHz
TPO	Power on time	TA = 25°C, CL = 1nF, IP=IPR(max) applied	-	190	-	us
TR	Rise time	IP = IPR(max), A = 25°C, CL = 1nF	-	3	-	us
TPD	Propagation Delay	IP = IPR(max), TA = 25°C, CL = 1nF	-	2	-	us
TRESP	Response Time	IP = IPR(max), TA = 25°C, CL = 1nF	-	4	5	us
VOL	Analog Output Low Saturation Level	RL>=4.7KΩ	-	-	0.3	V
VOH	Analog Output High Saturation Level	RL>=4.7KΩ	VCC-0.3	-	-	V
CL	Output CAP Load	OUT to GND	-	1	10	nF
ROUT	DC Output resistance		-	-	5	Ω
RL	Output RES Load	OUT to GND	4.7	-	-	KΩ
		OUT to VCC	4.7	-	-	KΩ
RF(int)	Internal filter resistance		-	1.8	-	KΩ
IND	Noise Density	Input-referenced noise density; TA = 25°C, CL = 1 nF	-	450	-	uA/√Hz
ELIN	Nonlinearity error	Through full range of IP	-1.5	-	1.5	%
ERAT_SNST	Ratiometry Sensitivity Error	VCC = 4.5 to 5.5 V, TA = 25°C	-	±1.5	-	%
ERAT_VOQ	Ratiometry Quiescent Voltage Output Error	VCC = 4.5 to 5.5 V, TA = 25°C	-	±1	-	%

* Device may be operated at higher primary current levels, ambient temperatures, and internal leadframe temperatures, provided the Maximum Junction Temperature, is not exceeded.

Continued on the next page...

Electrical Specifications (*continued*)

At T_A =-40~125 ℃, V_{CC}=5V (unless otherwise specified)

Symbol	Parameters	Test Condition	Min	Typ	Max	Unit
CMFRR	Common Mode Field Rejection Ratio	Uniform external magnetic field	-	40	-	dB
SNST(match)	Hall Plate Sensitivity Matching	TA = 25°C		±1	-	%
VPORH	Power-On Reset High Voltage	TA = 25°C, VCC rising	3.75	4	4.25	V
VPORL	Power-On Reset Low Voltage	TA = 25°C, VCC falling	-	3.5	-	V
VPORHYS	Power-On Reset Hysteresis	TA = 25°C	-	0.5	-	V
TPORR	Power-On Reset Release Time	TA = 25°C, VCC rising	-	30	-	us
TPORA	Power-On Reset Analog Delay	TA = 25°C, VCC rising	-	5	-	us
ISCLP	Source Current of Over-Current-Limit	-	-	80	-	mA
ISCLN	Sink Current of Over-Current-Limit	-	-	40	-	mA
TSCLD	Detect Time for Over-Current-Limit	TA = 25°C, IOUT>ISCLP or IOUT<ISCLN	-	7	-	us
TSCLR	Release Time for Over-Current-Limit	TA = 25°C	-	0.62	-	ms

* Device may be operated at higher primary current levels, ambient temperatures, and internal leadframe temperatures, provided the Maximum Junction Temperature, is not exceeded.

11.6 Accuracy Specifications

MT9222WT-20BR5 At T_A =-40~125 ℃, V_{CC}=5V (unless otherwise specified)

Symbol	Parameters	Test Condition	Min	Typ	Max	Unit
IPR	Optimized Input Current Range		-20	-	20	A
SNST	Sensitivity	-20A≤IP≤20A	-	100	-	mV/A
VOQ	Zero-Current Output Voltage		-	V_{CC}×0.5	-	V
VOE	Zero-Current Output Error	IP=0 A, TA=25°C	-10	-	10	mV
		IP=0 A, TA=-40°C to 25°C	-25	-	25	mV
		IP=0 A, TA=25°C to 125°C	-25	-	25	mV
ESNST	Sensitivity Error	IP=20A, TA=25°C	-	±1.1	-	%
		IP=20A, TA=-40°C to 25°C	-	±2.5	-	%
		IP=20A, TA=25°C to 125°C	-	±2.5	-	%
ETOT	Total Output Error	IP=20A, TA=25°C	-	±1.5	-	%
		IP=20A, TA = −40°C to 25°C	-	±3.5	-	%
		IP=20A, TA = 25°C to 125°C	-	±3.5	-	%

* Device may be operated at higher primary current levels, ambient temperatures, and internal leadframe temperatures, provided the Maximum Junction Temperature, is not exceeded.

MT9222
Fully Integrated, Hall Effect-Based Linear Current Sensor IC with
4.8 kV High-Isolation SOP-16 wide Body Package

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MT9222WT-25BR5 At T_A =-40~125 ℃, V_{CC}=5V (unless otherwise specified)

Symbol	Parameters	Test Condition	Min	Typ	Max	Unit
IPR	Optimized Input Current Range		-25	-	25	A
SNST	Sensitivity	-25A≤IP≤25A	-	80	-	mV/A
VOQ	Zero-Current Output Voltage		-	$V_{CC}×0.5$	-	V
VOE	Zero-Current Output Error	IP=0 A, TA=25°C	-10	-	10	mV
		IP=0 A, TA=-40°C to 25°C	-25	-	25	mV
		IP=0 A, TA=25°C to 125°C	-25	-	25	mV
ESNST	Sensitivity Error	IP=25A, TA=25°C	-	±1.1	-	%
		IP=25A, TA=-40°C to 25°C	-	±2.5	-	%
		IP=25A, TA=25°C to 125°C	-	±2.5	-	%
ETOT	Total Output Error	IP=25A, TA=25°C	-	±1.5	-	%
		IP=25A, TA = −40°C to 25°C	-	±3.5	-	%
		IP=25A, TA = 25°C to 125°C	-	±3.5	-	%

* Device may be operated at higher primary current levels, ambient temperatures, and internal leadframe temperatures, provided the Maximum Junction Temperature, is not exceeded.

MT9222WT-30BR5 At T_A =-40~125 ℃, V_{CC}=5V (unless otherwise specified)

Symbol	Parameters	Test Condition	Min	Typ	Max	Unit
IPR	Optimized Input Current Range		-30	-	30	A
SNST	Sensitivity	-30A≤IP≤30A	-	66.6	-	mV/A
VOQ	Zero-Current Output Voltage		-	$V_{CC}×0.5$	-	V
VOE	Zero-Current Output Error	IP=0 A, TA=25°C	-10	-	10	mV
		IP=0 A, TA=-40°C to 25°C	-25	-	25	mV
		IP=0 A, TA=25°C to 125°C	-25	-	25	mV
ESNST	Sensitivity Error	IP=30A, TA=25°C	-	±1.1	-	%
		IP=30A, TA=-40°C to 25°C	-	±2.5	-	%
		IP=30A, TA=25°C to 125°C	-	±2.5	-	%
ETOT	Total Output Error	IP=30A, TA=25°C	-	±1.5	-	%
		IP=30A, TA = −40°C to 25°C	-	±3.5	-	%
		IP=30A, TA = 25°C to 125°C	-	±3.5	-	%

* Device may be operated at higher primary current levels, ambient temperatures, and internal leadframe temperatures, provided the Maximum Junction Temperature, is not exceeded.

MT9222
Fully Integrated, Hall Effect-Based Linear Current Sensor IC with
4.8 kV High-Isolation SOP-16 wide Body Package

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MT9222WT-40UR5 At T_A =-40~125 ℃, V_{CC}=5V (unless otherwise specified)

Symbol	Parameters	Test Condition	Min	Typ	Max	Unit
IPR	Optimized Input Current Range		0	-	40	A
SNST	Sensitivity	0A≤IP≤40A	-	100	-	mV/A
VOQ	Zero-Current Output Voltage		-	V_{CC}×0.1	-	V
VOE	Zero-Current Output Error	IP=0 A, TA=25°C	-10	-	10	mV
		IP=0 A, TA=-40°C to 25°C	-25	-	25	mV
		IP=0 A, TA=25°C to 125°C	-25	-	25	mV
ESNST	Sensitivity Error	IP=40A, TA=25°C	-	±1.1	-	%
		IP=40A, TA=-40°C to 25°C	-	±2.5	-	%
		IP=40A, TA=25°C to 125°C	-	±2.5	-	%
ETOT	Total Output Error	IP=40A, TA=25°C	-	±1.5	-	%
		IP=40A, TA = −40°C to 25°C	-	±3.5	-	%
		IP=40A, TA = 25°C to 125°C	-	±3.5	-	%

* Device may be operated at higher primary current levels, ambient temperatures, and internal leadframe temperatures, provided the Maximum Junction Temperature, is not exceeded.

MT9222WT-50UR5 At T_A =-40~125 ℃, V_{CC}=5V (unless otherwise specified)

Symbol	Parameters	Test Condition	Min	Typ	Max	Unit
IPR	Optimized Input Current Range		0	-	50	A
SNST	Sensitivity	0A≤IP≤50A	-	80	-	mV/A
VOQ	Zero-Current Output Voltage		-	V_{CC}×0.1	-	V
VOE	Zero-Current Output Error	IP=0 A, TA=25°C	-10	-	10	mV
		IP=0 A, TA=-40°C to 25°C	-25	-	25	mV
		IP=0 A, TA=25°C to 125°C	-25	-	25	mV
ESNST	Sensitivity Error	IP=30A, TA=25°C	-	±1.1	-	%
		IP=30A, TA=-40°C to 25°C	-	±2.5	-	%
		IP=30A, TA=25°C to 125°C	-	±2.5	-	%
ETOT	Total Output Error	IP=30, TA=25°C	-	±1.5	-	%
		IP=30A, TA = −40°C to 25°C	-	±3.5	-	%
		IP=30A, TA = 25°C to 125°C	-	±3.5	-	%

* Device may be operated at higher primary current levels, ambient temperatures, and internal leadframe temperatures, provided the Maximum Junction Temperature, is not exceeded.

MT9222WT-50BR5 At T_A =-40~125 ℃, Vcc=5V (unless otherwise specified)

Symbol	Parameters	Test Condition	Min	Typ	Max	Unit
IPR	Optimized Input Current Range		-50	-	50	A
SNST	Sensitivity	-50A≤IP≤50A	-	40	-	mV/A
VOQ	Zero-Current Output Voltage		-	$V_{CC}×0.5$	-	V
VOE	Zero-Current Output Error	IP=0 A, TA=25°C	-10	-	10	mV
		IP=0 A, TA=-40°C to 25°C	-25	-	25	mV
		IP=0 A, TA=25°C to 125°C	-25	-	25	mV
ESNST	Sensitivity Error	IP=30A, TA=25°C	-	±1.1	-	%
		IP=30A, TA=-40°C to 25°C	-	±2.5	-	%
		IP=30A, TA=25°C to 125°C	-	±2.5	-	%
ETOT	Total Output Error	IP=30A, TA=25°C	-	±1.5	-	%
		IP=30A, TA = −40°C to 25°C	-	±3.5	-	%
		IP=30A, TA = 25°C to 125°C	-	±3.5	-	%

* Device may be operated at higher primary current levels, ambient temperatures, and internal leadframe temperatures, provided the Maximum Junction Temperature, is not exceeded.

MT9222WT-65BR5 At T_A =-40~125 ℃, Vcc=5V (unless otherwise specified)

Symbol	Parameters	Test Condition	Min	Typ	Max	Unit
IPR	Optimized Input Current Range		-65	-	65	A
SNST	Sensitivity	-65A≤IP≤65A	-	30.8	-	mV/A
VOQ	Zero-Current Output Voltage		-	$V_{CC}×0.5$	-	V
VOE	Zero-Current Output Error	IP=0 A, TA=25°C	-10	-	10	mV
		IP=0 A, TA=-40°C to 25°C	-25	-	25	mV
		IP=0 A, TA=25°C to 125°C	-25	-	25	mV
ESNST	Sensitivity Error	IP=32.5A, TA=25°C	-	±1.1	-	%
		IP=32.5A, TA=-40°C to 25°C	-	±2.5	-	%
		IP=32.5A, TA=25°C to 125°C	-	±2.5	-	%
ETOT	Total Output Error	IP=32.5A, TA=25°C	-	±1.5	-	%
		IP=32.5A, TA = −40°C to 25°C	-	±3.5	-	%
		IP=32.5A, TA = 25°C to 125°C	-	±3.5	-	%

* Device may be operated at higher primary current levels, ambient temperatures, and internal leadframe temperatures, provided the Maximum Junction Temperature, is not exceeded.

12 Characteristic Definitions

Power On Time---TPO

When the supply is ramped to its operating voltage, the device requires a finite time to power its internal components before responding to an input magnetic field.

The Power-On Time (TPO) is defined as the time taken between the supply reaching the minimum operating voltage VCCmin (t1), and the output voltage to settling to within ±10% of its steady state value under an applied magnetic field (t2) (See Figure 5).
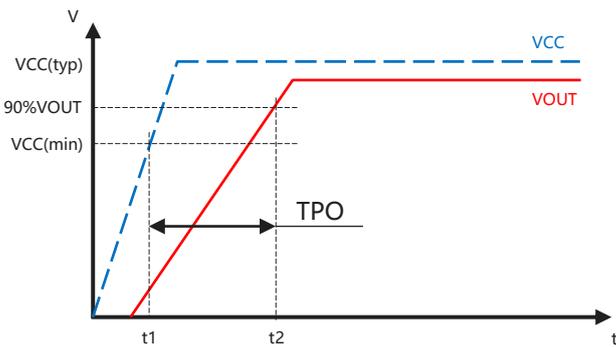
| Figure.5 | **Power On Time Definition** |

Propagation Delay---TPD

The time interval between a) when the primary current signal reaches 20% of its final value, and b) when the output reaches 20% of its final value (see Figure 6).
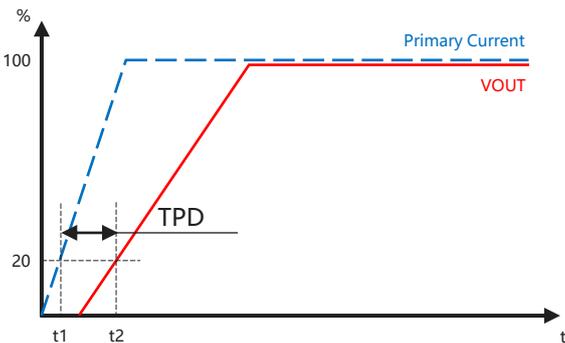
| Figure.6 | **Propagation Delay Definition** |

Rise Time---TR

Rise Time is the time interval between the sensor VOUT reaching 10% of its full scale value (t1), and it reaching 90% of its full scale value (t2). (see Figure 7). Both TR and TRESP can be negatively affected by any eddy current losses created if a conductive ground plane is used.
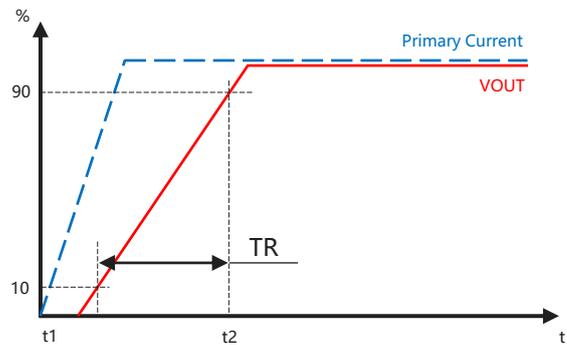
| Figure.7 | **Rise Time Definition** |

Response Time---TRESP

The time interval between a) when the primary current signal reaches 80% of its final value, and b) when the sensor reaches 80% of its output corresponding to the applied current. (see Figure 8). Both TR and TRESP can be negatively affected by any eddy current losses created if a conductive ground plane is used.
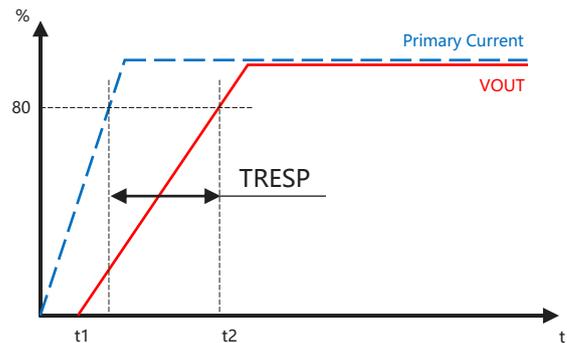
| Figure.8 | **Response Time Definition** |

MT9222
Fully Integrated, Hall Effect-Based Linear Current Sensor IC with
4.8 kV High-Isolation SOP-16 wide Body Package

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Zero-Current Output Voltage---VOQ

VOQ is the voltage output when the primary current is zero. For a unipolar supply voltage, it nominally remains at 0.5 × VCC for a bidirectional device and 0.1 × VCC for a unidirectional device. For example, in the case of a bidirectional output device, VCC=5V translates into VOQ=2.5V. Variation in VOQ from the nominal value is due to thermal drift and the resolution limits of voltage offset trimming in the factory.

Zero-Current Output Error---VOE

The deviation of the device output from its ideal quiescent value of 0.5 × VCC (bidirectional) or 0.1 × VCC (unidirectional) due to nonmagnetic causes. To convert this voltage to amp, divide by the device sensitivity (SNST).

Sensitivity---SNST

The Sensitivity in mV/A indicates how much the output changes when the primary current changes. It is the product of the magnetic circuit sensitivity (G/A) (1G = 0.1mT) and the linear IC amplifier gain (mV/G). The linear IC amplifier gain is programmed at the factory to optimize the sensitivity (mV/A) for the full-scale current of the device.

$$SNST=\left(\frac{VOUT\_IPOSx-VOUT\_INEGx}{IPOSx-INEGx}\right)$$

where IPOSx and INEGx are two current values with opposite polarities.

Total Output Error---ETOT

The accuracy represents the maximum deviation of the actual current output from its ideal current value. This is equivalent to the difference between the actual output voltage and the ideal output voltage, divided by the ideal sensitivity, relative to the current flowing through the primary conduction path:

$$ETOT(IP)=\left(\frac{VOUT\_(IP)-VOUT\_ideal(IP)}{SNST\_ideal*IP}\right)*100\%$$

Nonlinearity Sensitivity Error---ELIN

Ideally the primary current vs sensor output function is a straight line. The non-linearity is an indication of the worst deviation from this straight line. The ELIN in % is defined as:

$$ELIN=\left(\frac{SNST\_I1}{SNST\_I2}-1\right)*100\%$$

Where:

$$SNST\_I1=\left(\frac{VOUT\_IPOS1-VOUT\_INEG1}{IPOS1-INEG1}\right)$$

$$SNST\_I2=\left(\frac{VOUT\_IPOS2-VOUT\_INEG2}{IPOS2-INEG2}\right)$$

and IPOSx and INEGx are positive and negative current values, with respect to the quiescent voltage output such that |IPOS2| = |INEG2| = IPRmax, and |IPOS2| = 2 × |IPOS1| and |INEG2| = 2 × |INEG1|.

Ratiometry Error---ERAT

The MT9222 device features ratiometric output. This means that the Quiescent Voltage Output (VOQ) and sensitivity (SNST), are proportional to the Supply Voltage, VCC. In other words, when the supply voltage increases or decreases by a certain percentage, each characteristic also increases or decreases by the same percentage. Error is the difference between the measured change in the supply voltage relative to 5 V, and the measured change in each characteristic.

Ratiometry Quiescent Voltage Output Error---ERAT_VOQ

ERAT_VOQ, for a given supply voltage, is defined as:

$$ERAT\_VOQ=\left(\frac{VOQ(VCC)/VCC}{VOQ(5V)/5V}-1\right)*100\%$$

Ratiometry Sensitivity Error---ERAT_SNST

ERAT_SNST, for a given supply voltage, is defined as:

$$ERAT\_SNST=\left(\frac{SNST\_I1(VCC)/VCC}{SNST\_I1(5V)/5V}-1\right)*100\%$$

Power-On Reset---POR

The descriptions in this section assume temperature = 25°C, no output load (RL, CL) , and no the applied current is present.

Power-Up. At power-up, as VCC ramps up, the output is in a high-impedance state. When VCC crosses VPORH, the output will go to VCC/2 after POR Release counter (TPORR) + POR Analog delay (TPORA).

VCC drops below VCC(min) = 4.5 V. If VCC drops below VPORL, the output will be in a high-impedance state. If VCC recovers and exceeds VPORH, the output will go back to normal operation after POR Release counter (TPORR) + POR Analog delay (TPORA) (See Figure. 9).
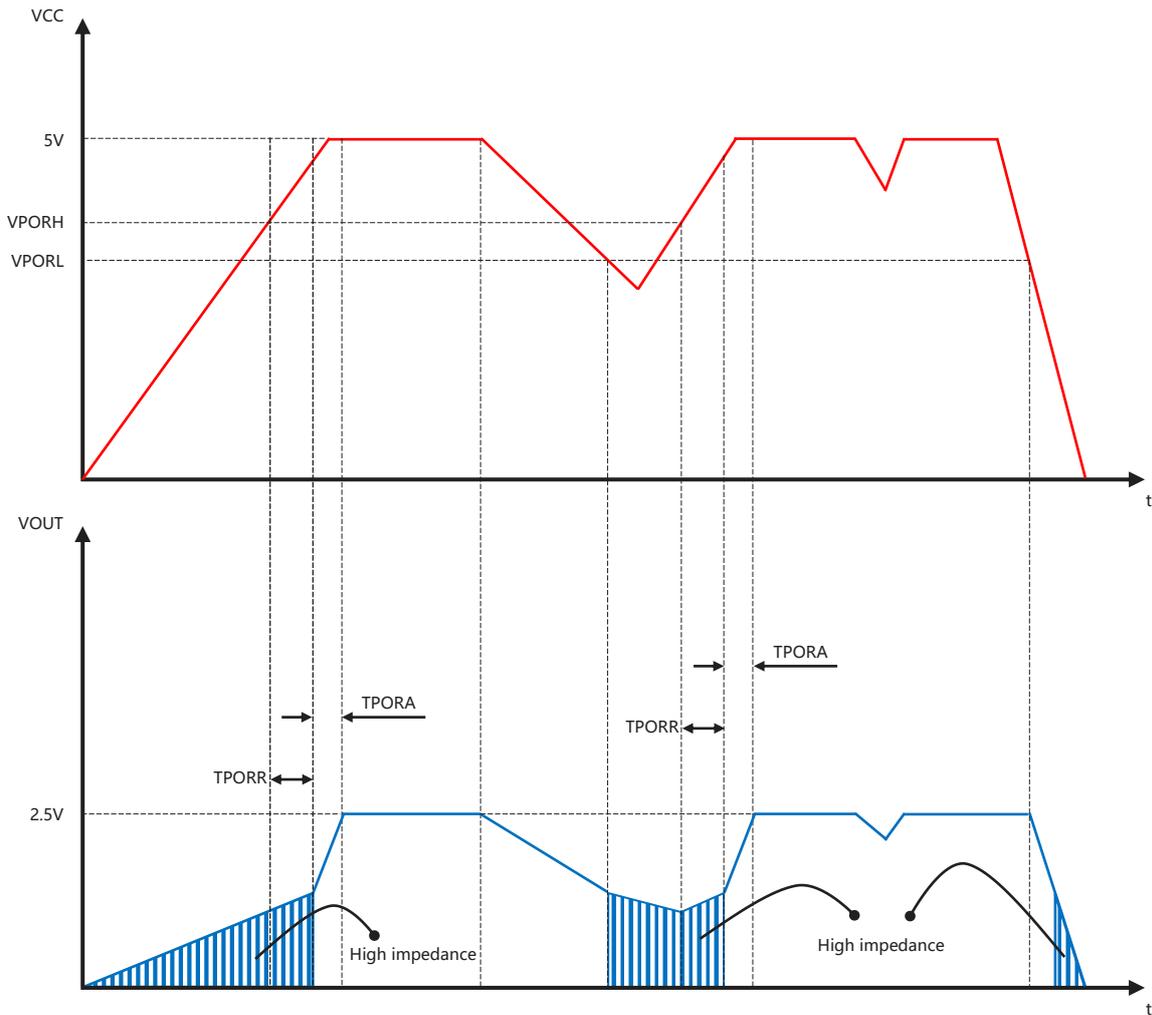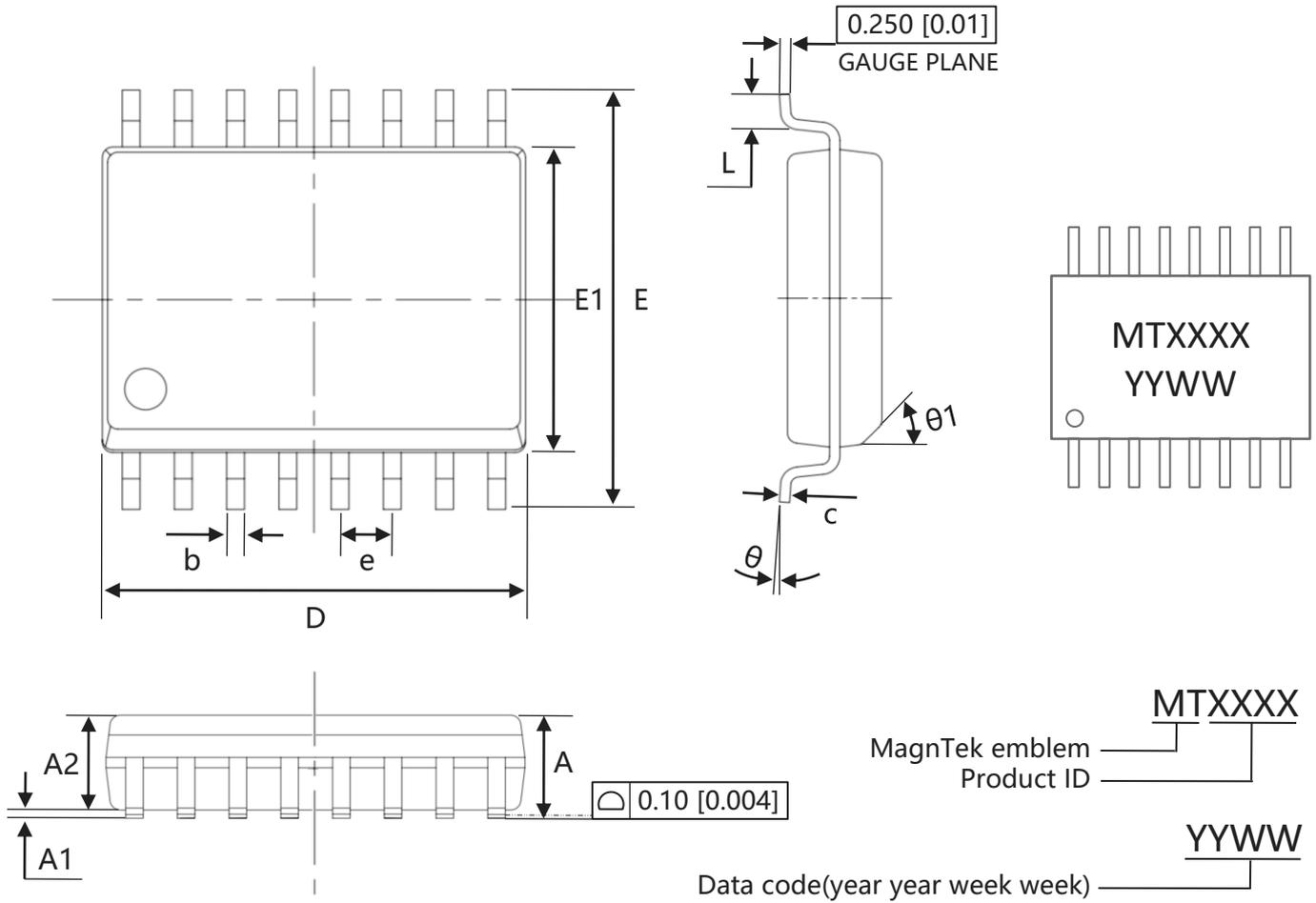

Figure.9   **Power-On Reset Definition**

MT9222
Fully Integrated, Hall Effect-Based Linear Current Sensor IC with
4.8 kV High-Isolation SOP-16 wide Body Package

MagnTek

13 Package Material Information　(For Reference Only – Not for Tooling Use)

13.1 SOP-16W Package Information

Symbol	Dimensions in Millimeters		Dimensions in Inches	
	Min	Max	Min	Max
A	2.350	2.650	0.093	0.104
A1	0.100	0.300	0.004	0.012
A2	2.050	2.550	0.081	0.100
b	0.330	0.510	0.013	0.020
c	0.230	0.320	0.009	0.013
D	10.10	10.50	0.398	0.413
E	10.00	10.63	0.394	0.419
E1	7.400	7.600	0.291	0.299
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0˚	8˚	0˚	8˚
θ1	45˚		45˚	

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